### NEW TCXO/VC-TCXO **ULTRA MINIATURE SIZE LOW PROFILE HIGH STABILITY**

TG-5006CJ

•Frequency range : 13 MHz to 52 MHz : 1.8 V / 2.8 V Supply voltage •Frequency / temperature characteristics

:  $\pm 0.5 \times 10^{-6}$  Max. or  $\pm 2.0 \times 10^{-6}$  Max.

•External dimensions: 2.0 x 1.6 x 0.73 mm

 Applications GPS.

Wireless communication devices

(CDMA, WCDMA, LTE, WiMAX, other)

Features High stability

Low supply voltage (1.8 V)

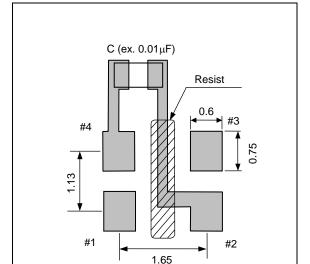


#### Specifications (characteristics)

Item	Symbol	Specifications		0 155 / 0
		VC-TCXO	TCXO	Conditions / Remarks
Output frequency range	fo	13.000 MHz to 52.000 MHz		
		16.367667 MHz, 16.368 MHz, 16.369 MHz,		Standard frequency
		19.2 MHz, 26 MHz and 38.4 MHz		
Supply voltage	Vcc	1.8 V ±0.1 V / 2.8 V ±0.14 V (Range :1.7 V to 3.3 V)		
Storage temperature	T_stg	-40 °C to +90 °C		Storage as single product.
Operating temperature	T_use	-30 °C to +85 °C		
Frequency tolerance	f_tol	$\pm 2.0 \times 10^{-6}$ Max.		After reflow, +25 °C
Frequency/temperature characteristics	fo-Tc	$\pm 0.5 \times 10^{-6}$ Max. / -30 °C to +85 °C		High stability version for GPS
		$\pm 2.0 \times 10^{-6}$ Max. / -30 °C to +85 °C		Standard stability version
		$\pm 2.0 \times 10^{-6}$ Max. / -40 °C to +85 °C (Option)		Customized product
Frequency/load coefficient	fo-Load	$\pm 0.2 \times 10^{-6}$ Max.		10 k $\Omega$ // 10 pF $\pm$ 10 %
Frequency/voltage coefficient	fo-Vcc	$\pm 0.2 \times 10^{-6}$ Max.		Vcc=1.8 V ±0.1 V or 2.8 V ±0.14 V
Frequency aging	f_age	$\pm 1.0 \times 10^{-6}$ Max.		+25 °C, First year, 13 MHz≦fo≦40 MHz
		$\pm 1.5 \times 10^{-6}$ Max.		+25 °C, First year, 40 MHz <fo≦52 mhz<="" td=""></fo≦52>
Current consumption	Icc	1.5 mA Max.		13 MHz≦fo≦26 MHz
		2.0 mA Max.		26 MHz <fo≦52 mhz<="" td=""></fo≦52>
Input resistance	Rin	500 kΩ Min.	_	Vc - GND (DC)
Frequency control range	f_cont	$\pm 8.0 \times 10^{-6} \text{ to } \pm 15.0 \times 10^{-6}$	—	Vc=0.9 V ±0.6 V (Vcc =1.8 V) or
				Vc=1.4 V ±1.0 V (Vcc =2.8 V)
Frequency change polarity		Positive polarity		
Symmetry	SYM	40 % to 60 %		GND level (DC cut)
Output voltage	$V_{pp}$	0.8 V Min.		Peak to Peak
Output load condition	Load_R	10 kΩ		DC cut capacitor = 0.01 μF
	Load_C	10 pF		

<sup>\*</sup> Note: Please contact us for requirements not listed in this specification.

# External dimensions (Unit:mm) Pin map Pin Connection VC-TCXO TCXO 1 N.C <u>1.</u>2 #3 GND 2 3 OUT 4 Vcc



(Unit:mm)

Footprint (Recommended)

To maintain stable operation, provide a 0.01uF to 0.1uF by-pass capacitor at a location as near as possible to the power source terminal of the crystal product (between Vcc - GND).

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

## Click to view similar products for epson manufacturer:

Other Similar products are found below:

MA-505 24.0000M-C3 ROHS MC-405 32.7680K-G3: ROHS S5U13L02P00C100 S5U13U11P00C100 SG5032CAN 10.000000M-TJGA3 SG5032VAN 200.000000M-KEGA3 SG-210STF 2.0480ML3 SG-531P 7.3728MC:ROHS X1G0044810005 SG7050CAN 10 MHZ SG-Writer-II S5U1C31W74T1300 S5U1C17W04T2100 IC Socket for 7050 case SG-210STF 40.0000ML TSX-3225 26.0000MF10Z-B6 EG-2121CA 200.0000M-LGPNB RTC-72423A S5U13513P00C100 SG-210STF 13.5600ML3 Q3851CA000055 XG-1000CA 50 MHZ EG-2121CA 644.53125MLGPA RX-8564LC:B3 PURE SN M160 MA-506 4.0000M-C3 ROHS EG-2121CA2000000M-LGPAL3 S5U13U00P00C100 FA-118T 52.0000ME12Z-AC3 S5U1C17001H3100 S5U13513R00C100 IC Socket for 5032 case FC-13A 32.7680KA-A SG-210STF 4.0960ML S5U13517P00C200 S5U13748P00C100 S5U1C17W18T2100 SG-310SCF 20.0000MM S5U13781R01C100 MA-506 25.0000M-C3:ROHS S5U1C17M13T2100 S5U1C17M13T1100 FA-238 25.0000MB50X-C3 RX-8803LC:UB3 PURE SN SG-3030LC 32.7680KB3, PURE SN SG-615P 8.0000MC3: ROHS Q3102JF010001 SG-3030JF 32.768KHZ B M150 S5U1C17W15T2100 FC-135 32.7680KA-K0 XG-2121CA 156.2500M-PGSNB FA-128 25.0000MF20X-WX